

MPS6534



PNP General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 500 mA. Sourced from Process 63. See PN2907A for characteristics.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	4.0	V
Ic	Collector Current - Continuous 800 r		mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

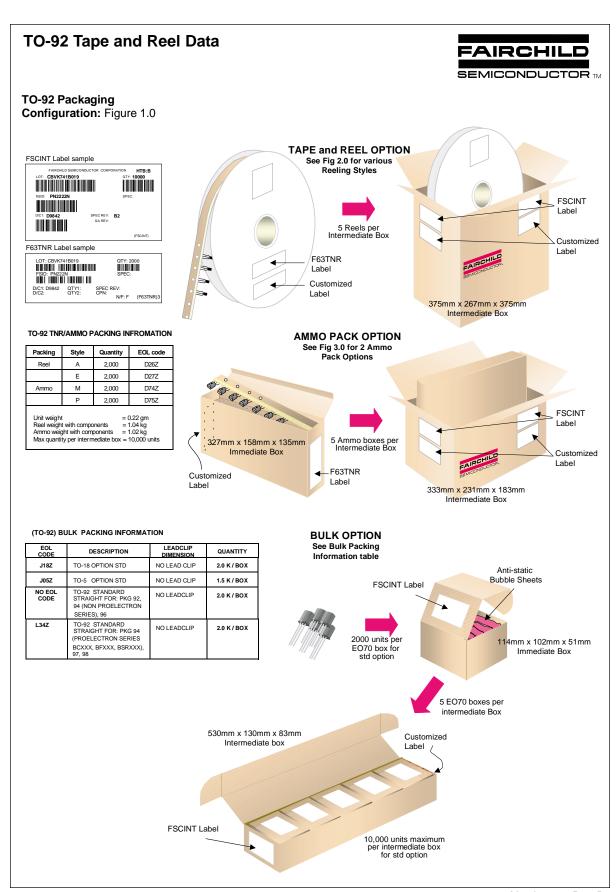
TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		MPS6534	
P _D	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

PNP General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_C = 10 \text{ mA}, I_B = 0$	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 10 \mu\text{A}, I_E = 0$	40		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10 \mu\text{A}, I_C = 0$	4.0		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 30 \text{ V}, I_{E} = 0$		50	nA
		$V_{CB} = 30 \text{ V}, I_{E} = 0, T_{A} = 60 ^{\circ}\text{C}$		2.0	μΑ
ON CHAF	RACTERISTICS*	V _{CB} = 30 V, I _E = 0, I _A = 60 °C		2.0	μΑ_
ON CHAF	RACTERISTICS* DC Current Gain	$V_{CE} = 1.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 1.0 \text{ V}, I_{C} = 100 \text{ mA}$	60 90 50	270	μΑ
		$V_{CE} = 1.0 \text{ V}, I_{C} = 10 \text{ mA}$	90		V
h _{FE}	DC Current Gain	$V_{CE} = 1.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 1.0 \text{ V}, I_{C} = 100 \text{ mA}$ $V_{CE} = 10 \text{ V}, I_{C} = 500 \text{ mA}$	90	270	
V _{CE(sat)}	DC Current Gain Collector-Emitter Saturation Voltage	$V_{CE} = 1.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 1.0 \text{ V}, I_{C} = 100 \text{ mA}$ $V_{CE} = 10 \text{ V}, I_{C} = 500 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 10 \text{ mA}$	90	270	V

^{*}Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

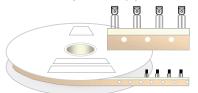


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TO-92 Tape and Reel Data, continued

TO-92 Reeling Style Configuration: Figure 2.0

Machine Option "A" (H)

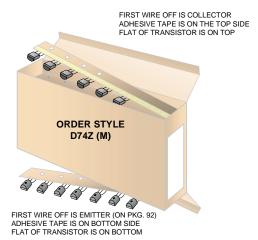


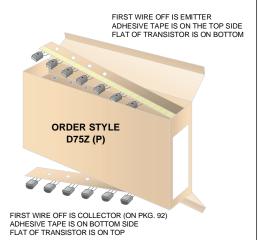
Style "A", D26Z, D70Z (s/h)

Machine Option "E" (J)

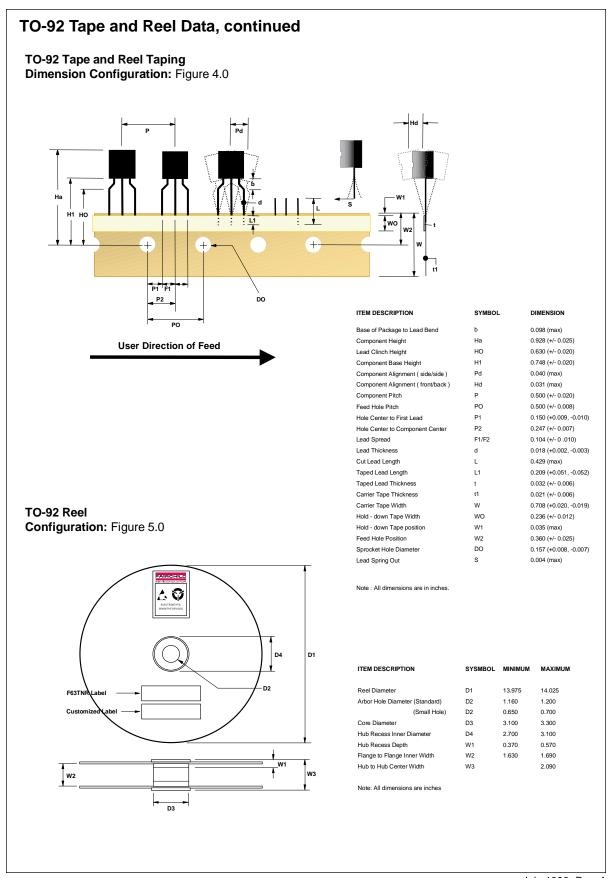
Style "E", D27Z, D71Z (s/h)

TO-92 Radial Ammo Packaging Configuration: Figure 3.0





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TO-92 Package Dimensions FAIRCHILD SEMICONDUCTOR TM TO-92 (FS PKG Code 92, 94, 96) Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters] Part Weight per unit (gram): 0.1977 0.185 4.70 0.170 4.32 TO-92 (92,94,96) 94 96 B F В В В D D 2 В S С G Ε Ø0.060 [Ø1.52] G В S С G 0.010 [0.254] DEEP 5.0°TYP.

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0.095 0.084 2.13

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